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LIQUIDUS TEMPERATURES OF Hg-RICH Hg-Cd-Te ALLOYS*

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The liquidus temperatures have been measured for ten $(Hg_{1-x}Cd_{x})_{y}Te_{1-y}$ compositions with $0.091 \le x \le 0.401$ and $0.544 \le y \le 0.952$. For metal-rich melts with the same x-value, the liquidus temperature increases with y for $0.5 \le y \le 0.7$. This behavior is attributed to a higher degree of association between Cd and Te than between Hg and Te in the melts.

Key Words: Mercury cadmium telluride, phase diagram, associated solutions.

The liquidus temperatures have been determined by differential thermal analysis (DTA) for the ten $(Hg_{1-x}, x_{1-y}, y_{1-y})$ compositions listed in Table I. The experimental apparatus and procedure were similar to those used previously,(1) except for two modifications; type S (Pt/Pt-10% Rh) thermocouples were used instead of type K (chromel-alumel) thermocouples, and the triple-point-ofwater cell and x-y recorder used previously were replaced by a data logger with isothermal, thermallycompensated junctions and a microcomputer to store

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Mass Mass of Cd of Te (g) (g)	0.644 5.986 0.636 5.000 0.649 4.380	1. 233 5. 862 1. 222 5. 580 1. 211 4. 943 2. 018 0. 581	1.836 5.847 1.938 5.120	2.423 5.727
Mass of Hg (g)	10 . 344 10 . 206 11 . 532	8.809 8.724 9.384 14.394	7.701 8.094	6.465
Free volume inside ampule (%)	20 19 22	23 17 32	19 17	30
Observed liquidus (°C)	733 + 4 751 + 3 773 + 4 788 + 4	792 + 3 823 + 3 819 + 3 849 + 4 806 + 5	841 + 3 868 + 4 895 + 4	884 + 4 907 <u>+</u> 4
Overall y	0.5 0.550 0.591 0.648	0.5 0.544 0.554 0.601 0.952	0. 5 0. 544 0. 589	0.5 0.545
Overall x	0.100 0.100 0.100 0.001	0.200 0.200 0.200 0.200 0.200	0. 302 0. 299 0. 299	0.404 0.401

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the data. As in Ref. 1, the melting point of antimony (630.74°C) was used as the temperature calibration point during each experimental run. A typical DTA curve is shown in Fig. 1. The measured liquidus temperatures, elemental masses, and free volumes inside the ampules are included in Table I. Additional experimental details are given in Ref. 2.

Because the partial vapor pressures of Hg over the alloy melts are expected to be much larger than the partial pressures of Cd and Te,(3,4) the preferential evaporation of mercury into the ampule free volume alters both the Te/metal and Cd/Hg fractions. Hence, the actual melt compositions at the liquidus are somewhat higher in x and somewhat lower in y than the values listed in Table I. The precise melt compositions cannot be calculated from the masses of the elements and the free volume in an ampule because of the lack of vapor pressure data for metal-rich melts. However, based on the composition dependence of the vapor pressures over the Hg-Te binary melts, the corrections to x and y are estimated to be less than



Figure 1. Typical differential-thermal-analysis record

-0.005 and +0.006, respectively, for nine of the samples. For the x=0.401, y=0.545 sample, the corrections may be as large as -0.014 and +0.009, respectively, because of the combination of the relatively high temperature and 30% free volume in the ampule.

The major recognized sources of error in the liquidus temperatures are the uncertainty in the temperature measurements and the subjectivity in selecting the proper liquidus points from the DTA curves. Estimates of the uncertainties associated with the temperature measurements were obtained from calibration runs using an ampule containing silver as a DTA sample. The calibration runs indicated a maximum discrepancy of 1.5° C between the actual melting temperature of silver (961.93°C) and the value measured relative to the melting temperature of Sb in the DTA apparatus. The DTA signals were recorded at 1° C intervals, which implies an additional inherent uncertainty of $\pm 0.5^{\circ}$ C. Thus, the uncertainties arising from temperature measurements ranged from about $\pm 0.5^{\circ}$ C at the melting point of Sb to about $\pm 2^{\circ}$ C at the melting point of Ag.

In contrast to the behavior of the $Hg_{y}Te_{1-y}(5)$ and $Cd_{y}Te_{1-y}(6)$ binary systems, for a given x-value between 0.1 and 0.4, the liquidus temperature of the metal-rich melts increases with decreasing Te-fraction in the range 0.5<y<0.7. In some cases, the liquidus temperatures are larger by more than 50°C than the corresponding pseudobinary values. This interesting behavior was first noted in Ref. 7. We believe that this behavior is a direct consequence of a higher degree of association between Cd and Te than between Hg and Te in the melts, as suggested by the respective Cd + Te Z CdTe and Hg + Te Z HgTe equilibrium constants.(8-10) That is, the preferential affinity of Te for Cd causes the alloys to become more like CdTe in character as the Te fraction is decreased. Recent calculated values of the liquidus isotherms by Tung et al.(10) are in fair to good agreement with our experimental results. Liquidus temperatures as high as 500°C have been observed for compositions with less than 1 at. % Cd.(11, 12) A more quantitative analysis of the results in terms of a generalized associated solution model(9) for the ternary system is in progress.

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